

CCD thickness investigation

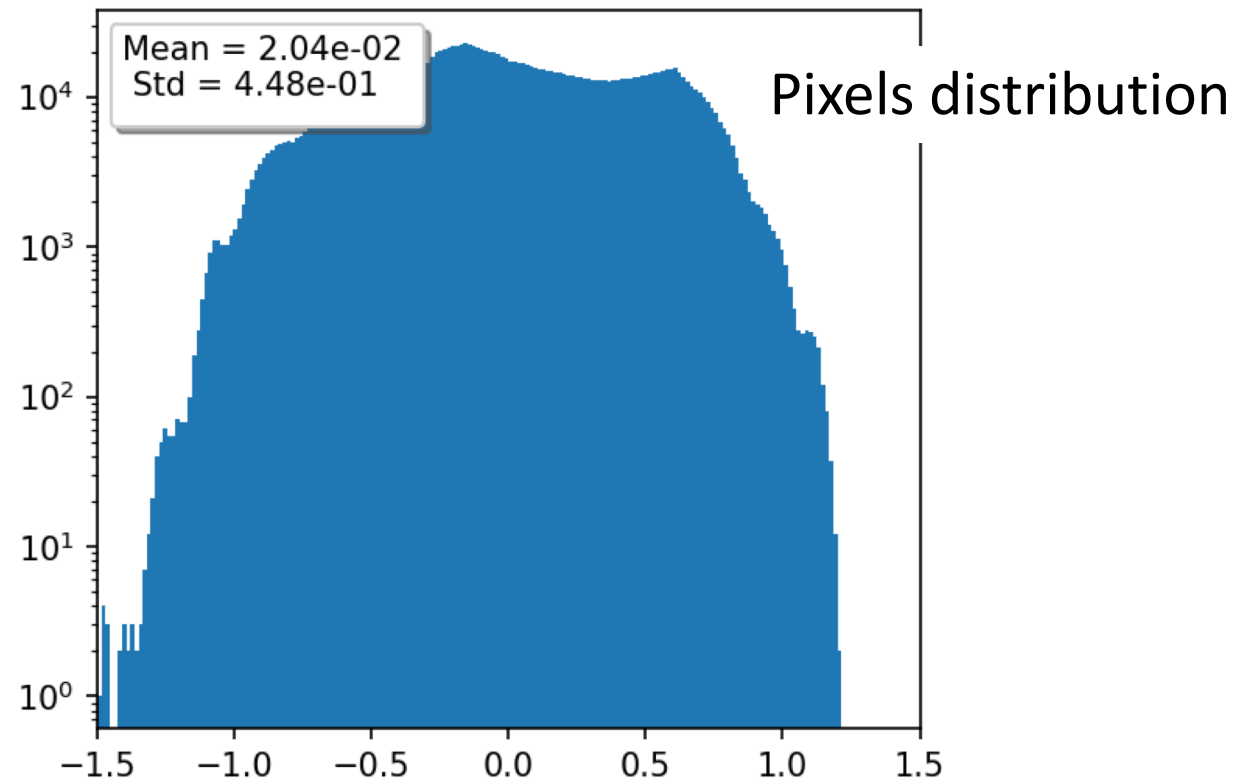
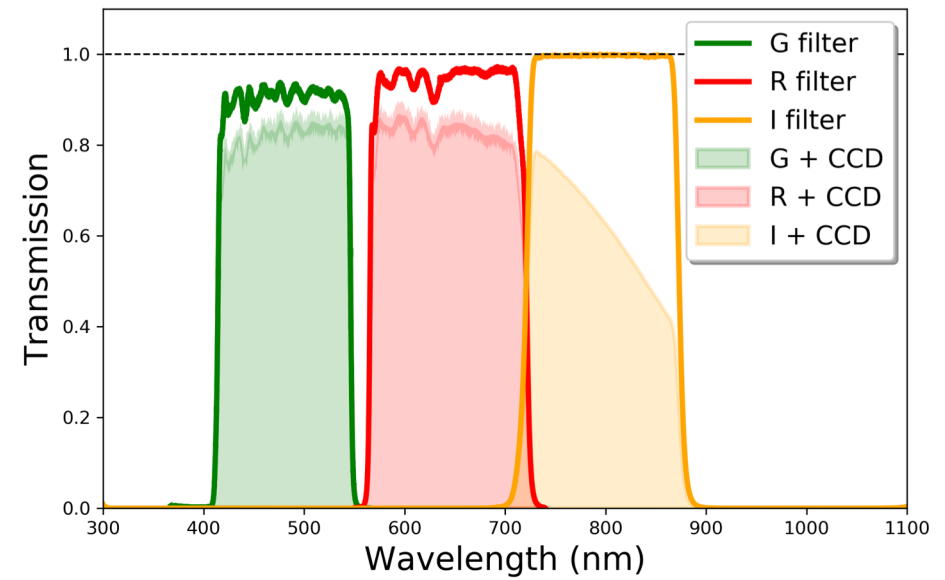
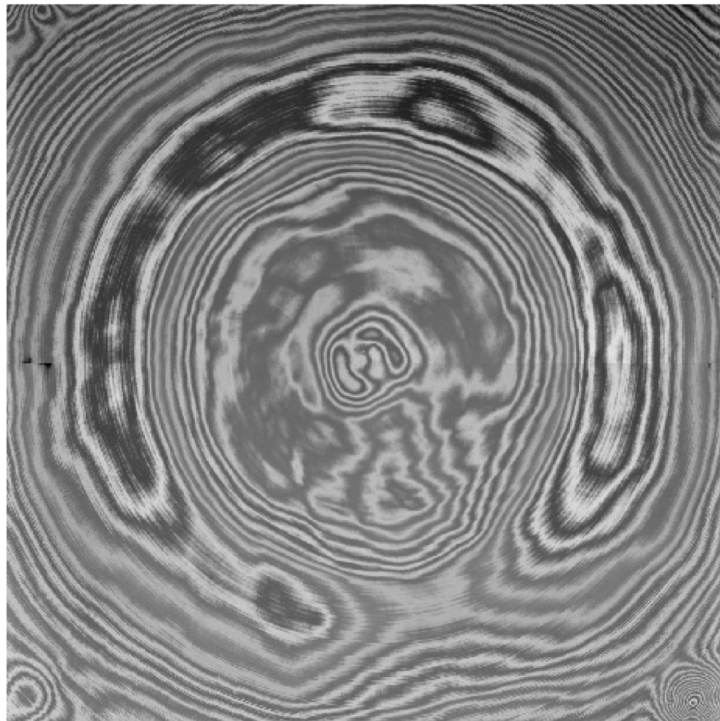
Philippe Rosnet
Laboratoire de Physique de Clermont
Université Clermont Auvergne – CNRS/IN2P3

with

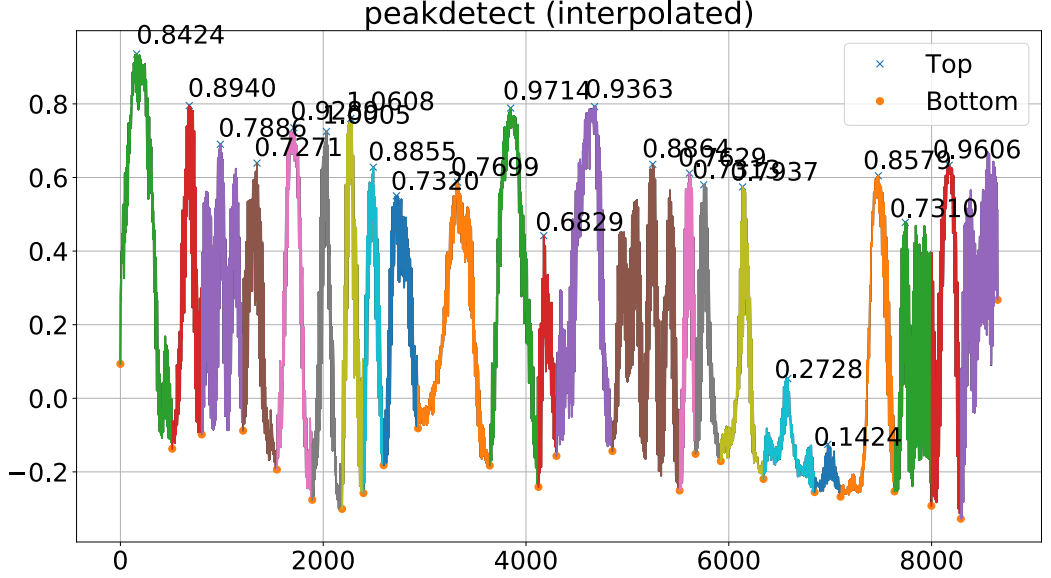
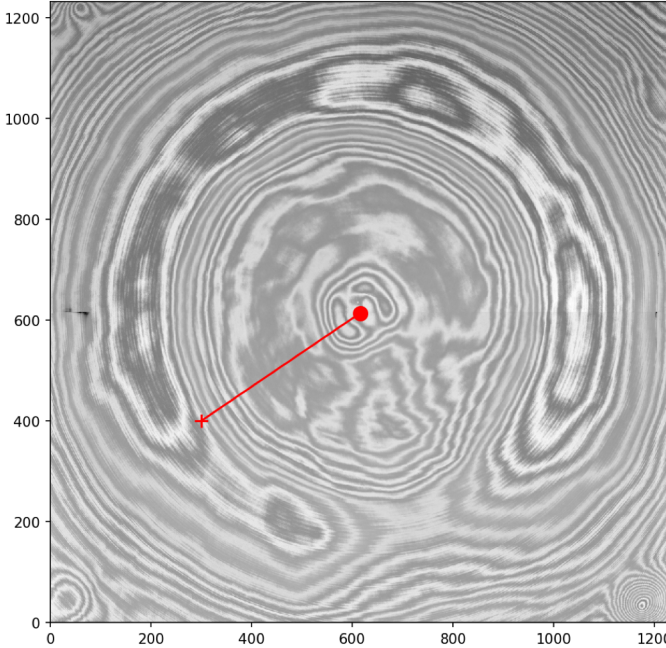
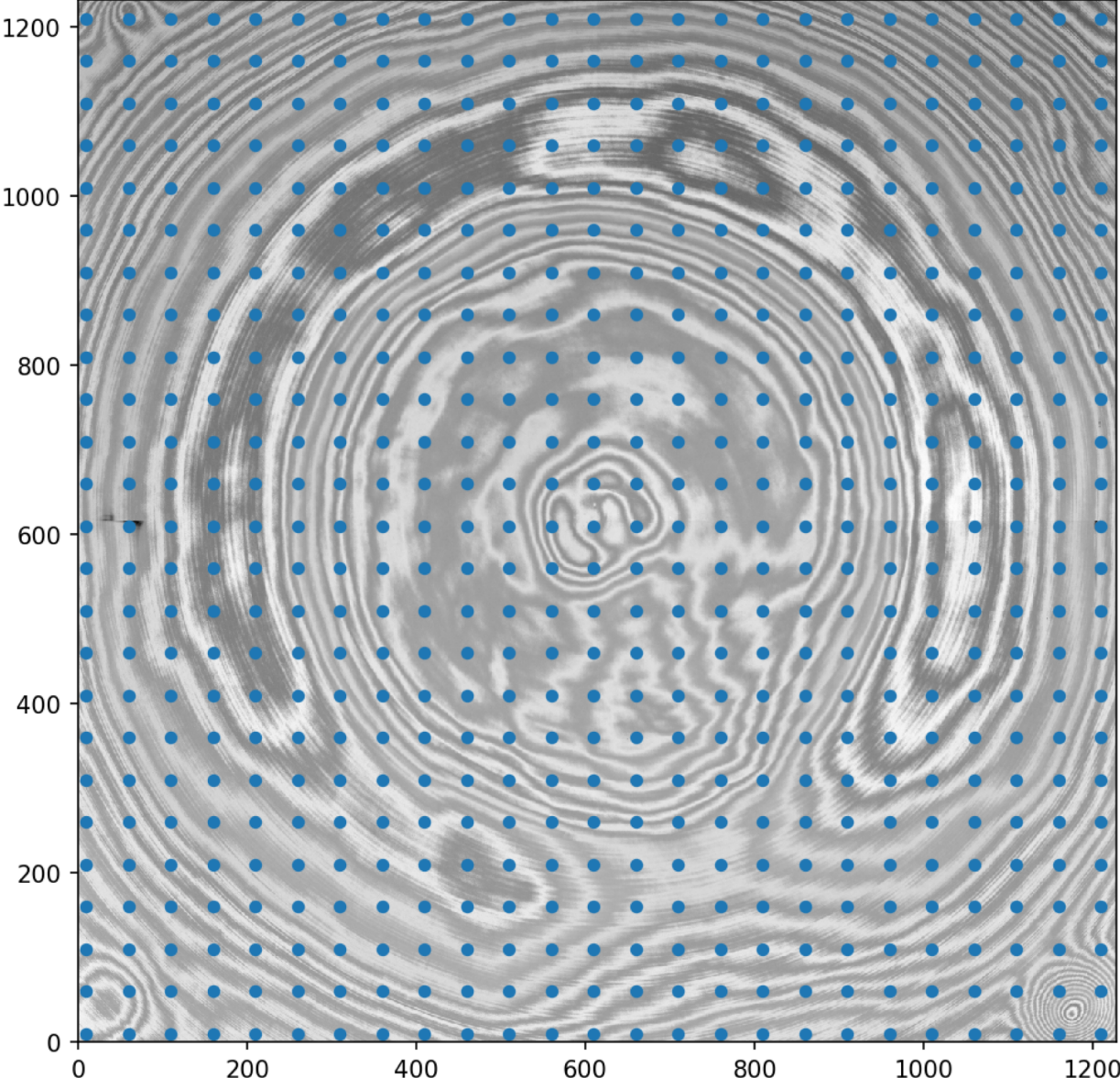
Roger Smith, Michael Coughlin and Michael Medford

Initial idea: use CCD fringing pattern from PCA analysis of I-band images (M. Medford) to deduce CCD thickness profile

CCD 01 fringing map

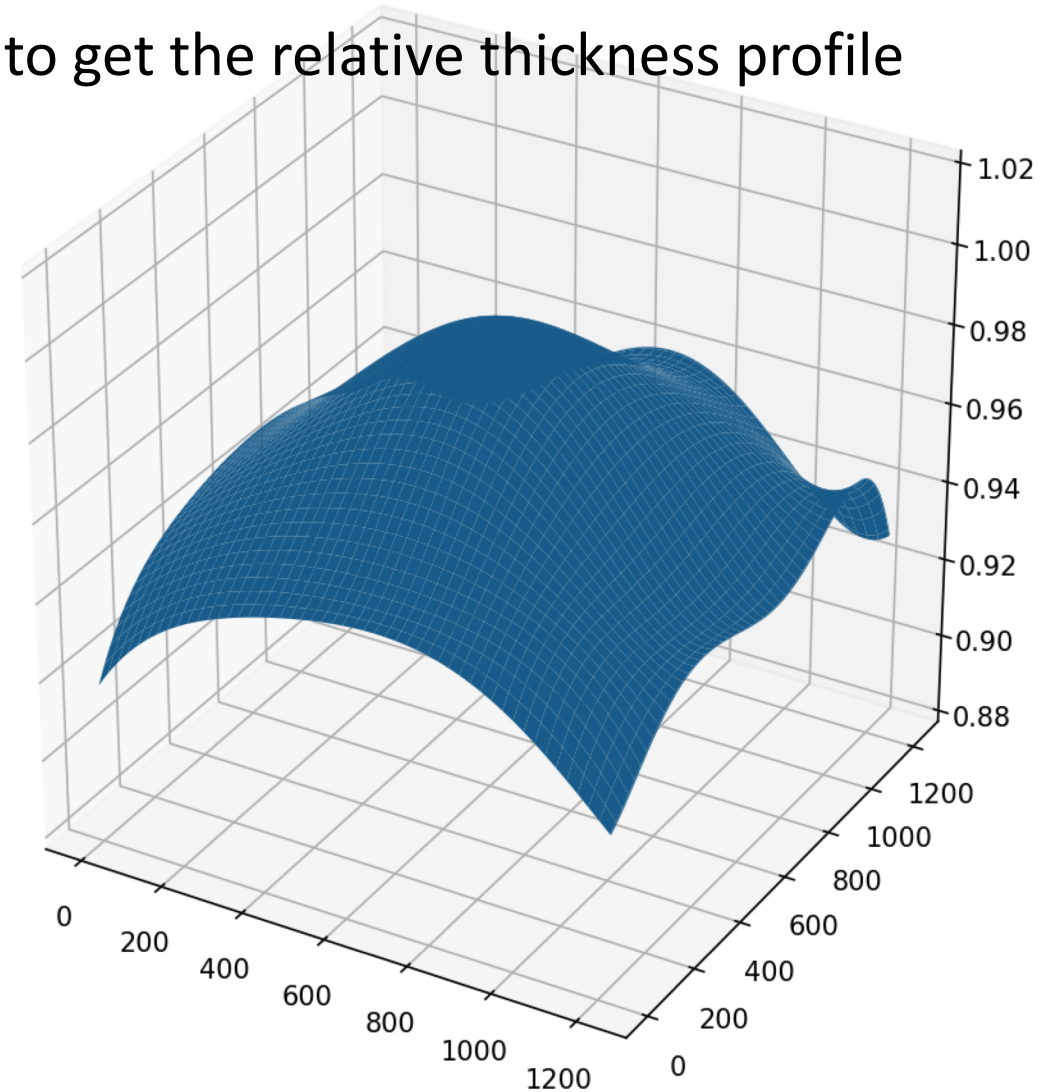
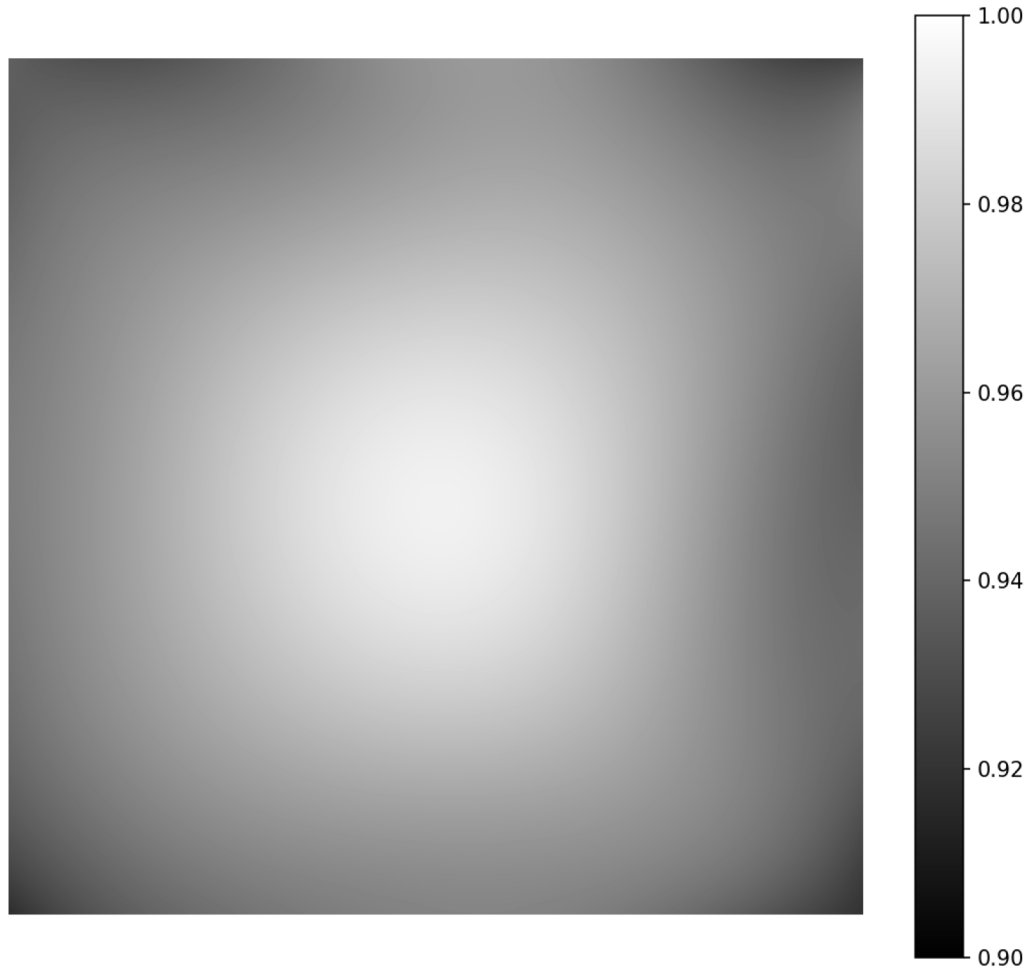


Point grid used by Michael Coughlin to count fringing from the CCD centre (CCD 01)

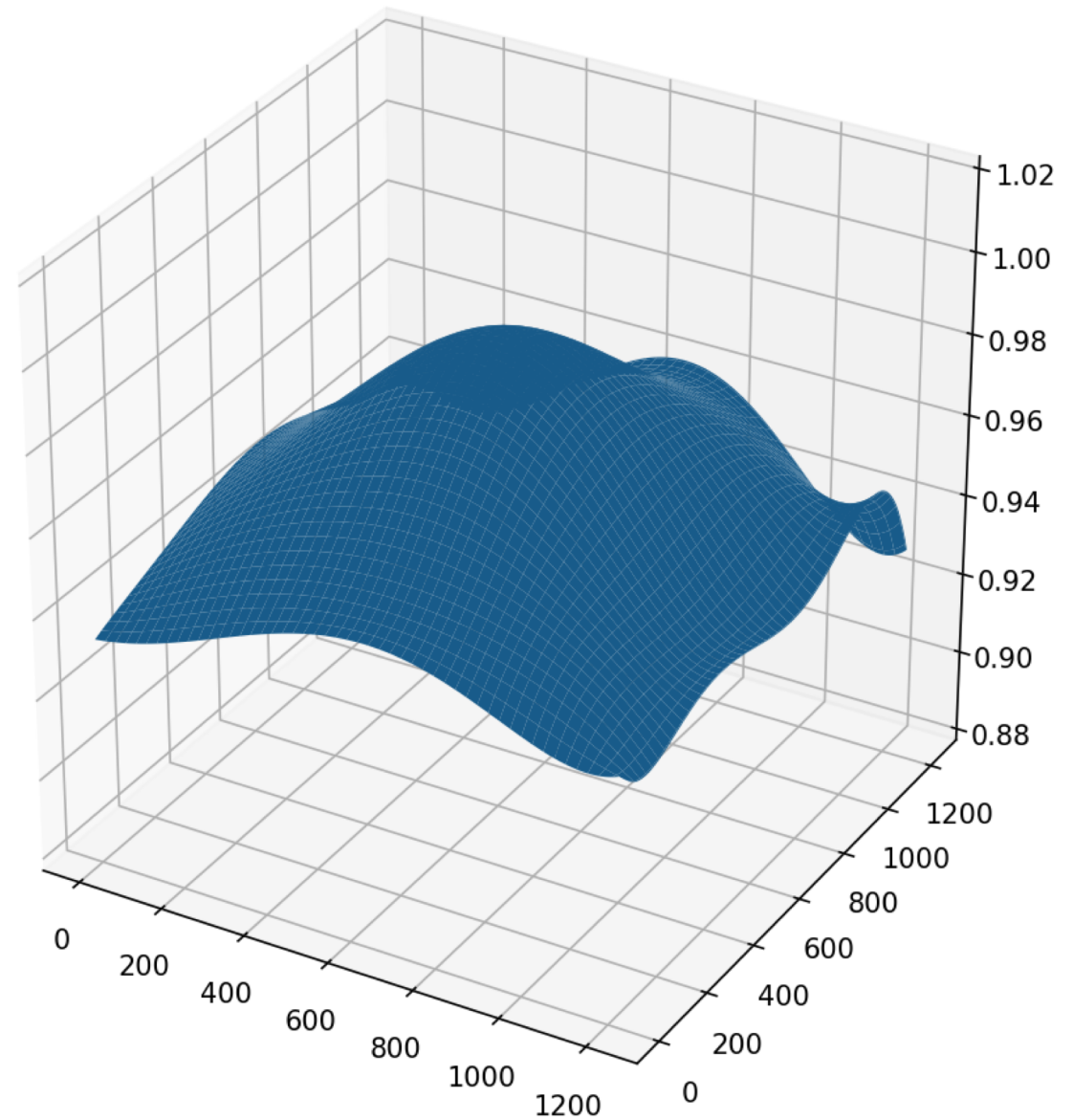
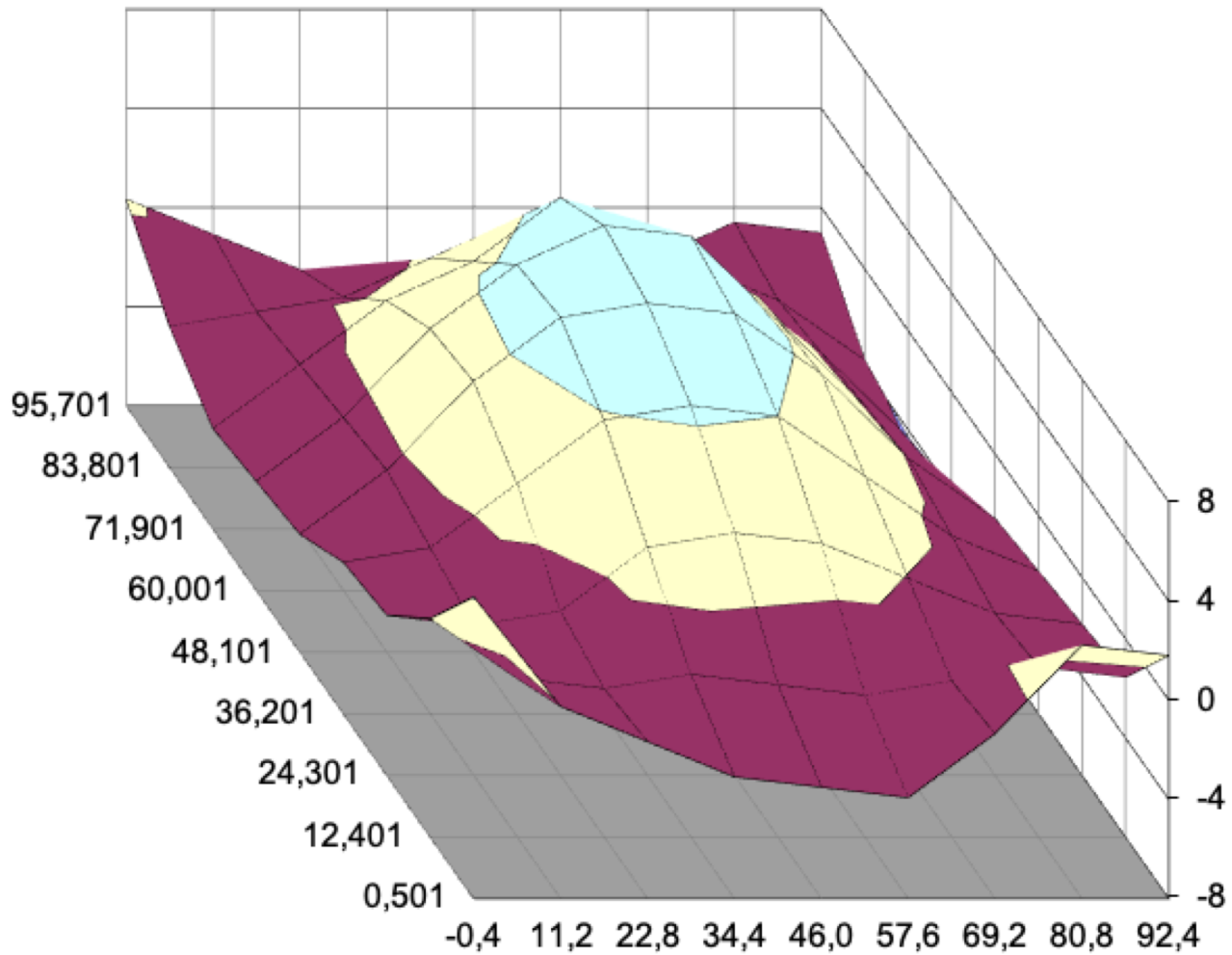


From fringing map to thickness profile

- Thickness variation : $\delta d = \pm n_{\text{Fringes}} \frac{\lambda}{2n_{\text{Si}}}$ with $\lambda = 800$ nm and $n_{\text{Si}} = 3.6$
- Interpolated 2D-map using 2D-spline technique to get the relative thickness profile



Comparison with e2v thickness variation measurements with local correction on corners (bottom left and right and top left)



Forward modelling: from thickness profile to fringing map

Transmitted intensity:
$$I = I_0 \frac{(1 - r)^2}{1 + r^2 - 2r \cos \Delta\phi}$$

with I_0 = incident light intensity
 r = interface reflexion coefficient

$$\Delta\phi = 2 \frac{2\pi}{\lambda} n_{Si} d \cos \beta$$

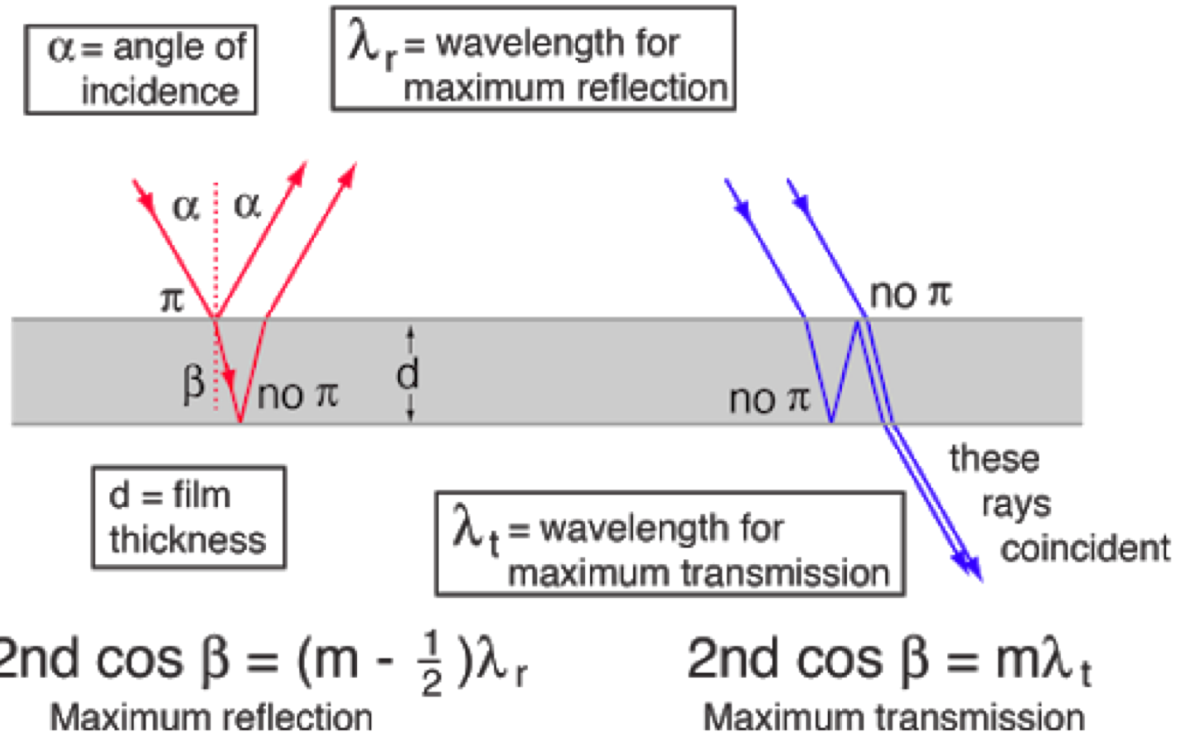
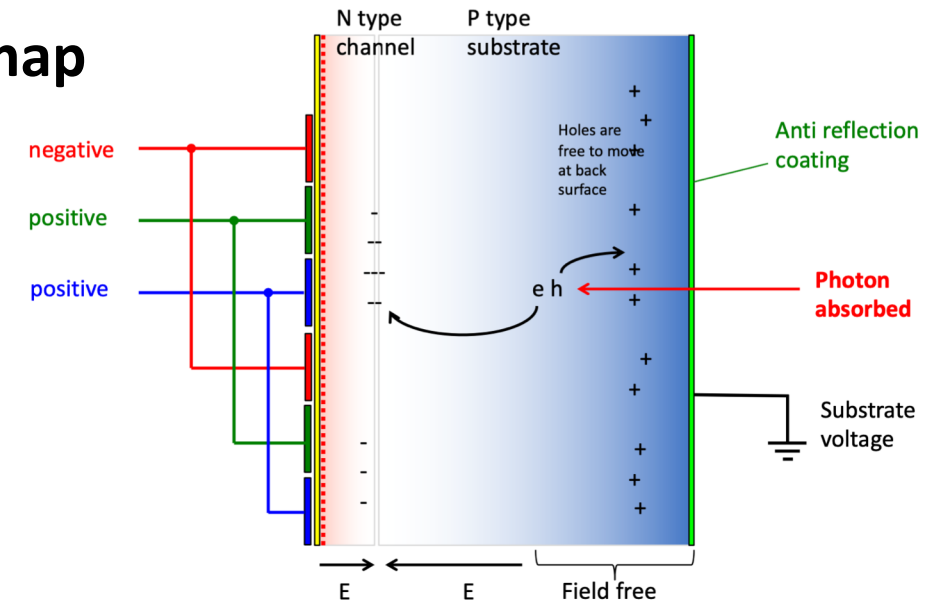
d = thickness

n_{Si} = Silicon refractive index

β = angle of refraction

Default input values

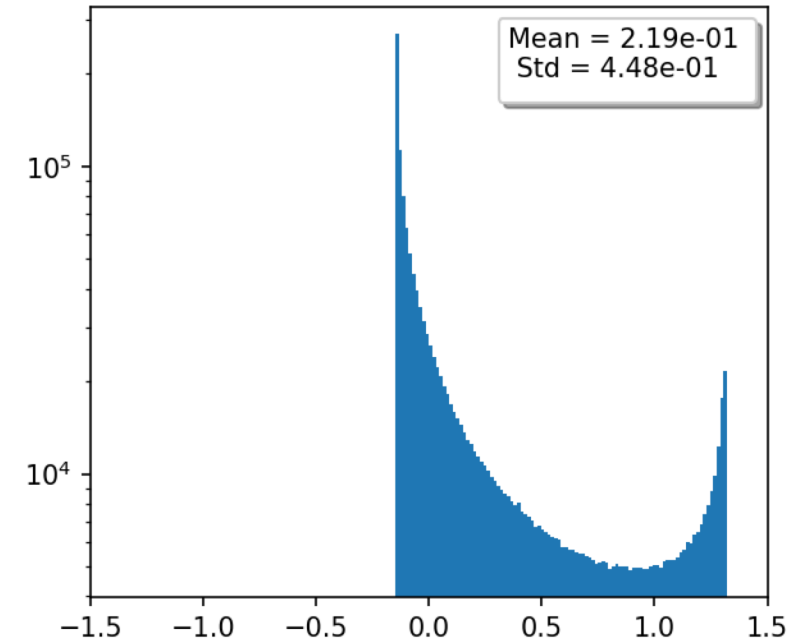
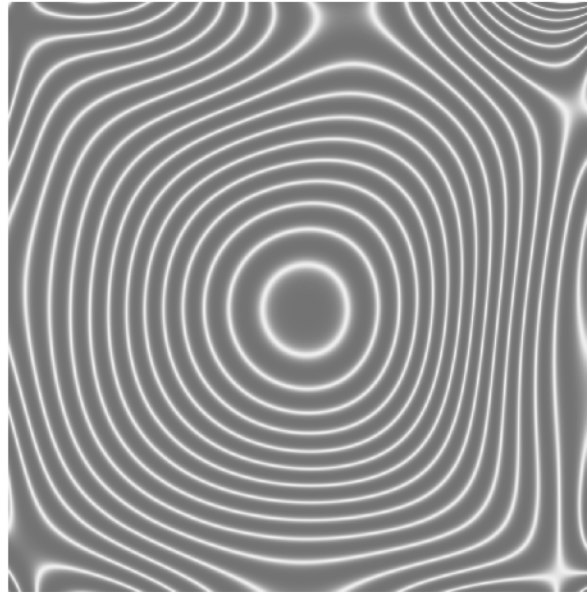
- $r = 0.5$
- $d = 30 \mu\text{m}$
- $n_{Si} = 3.6$
- $\beta = 0$



Forward modelling with profile from fringing pattern

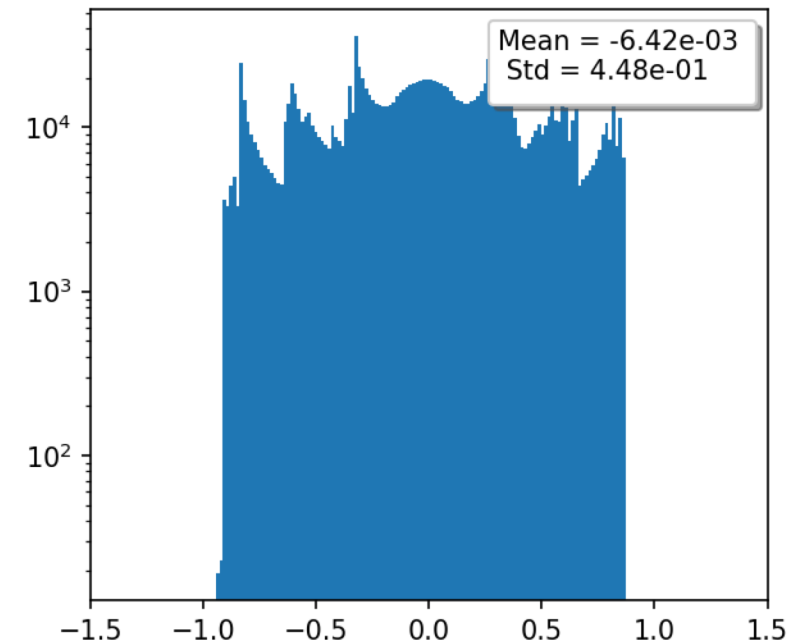
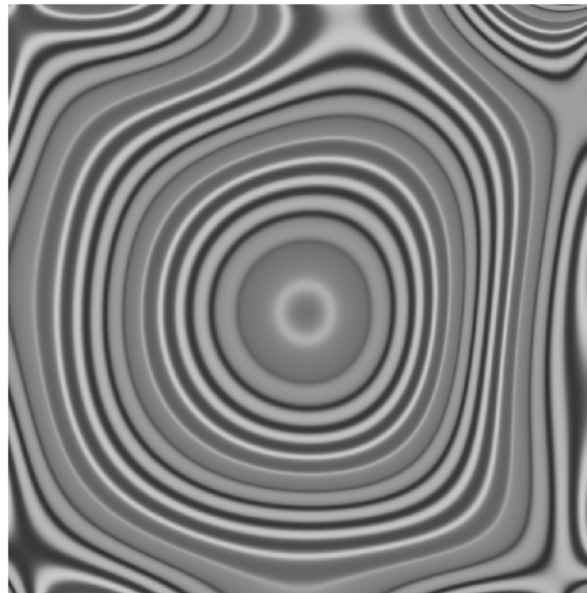
Mean fringing maps with

- $\lambda = 800$ nm
- $d = 30$ μm
- $r = 0.5$



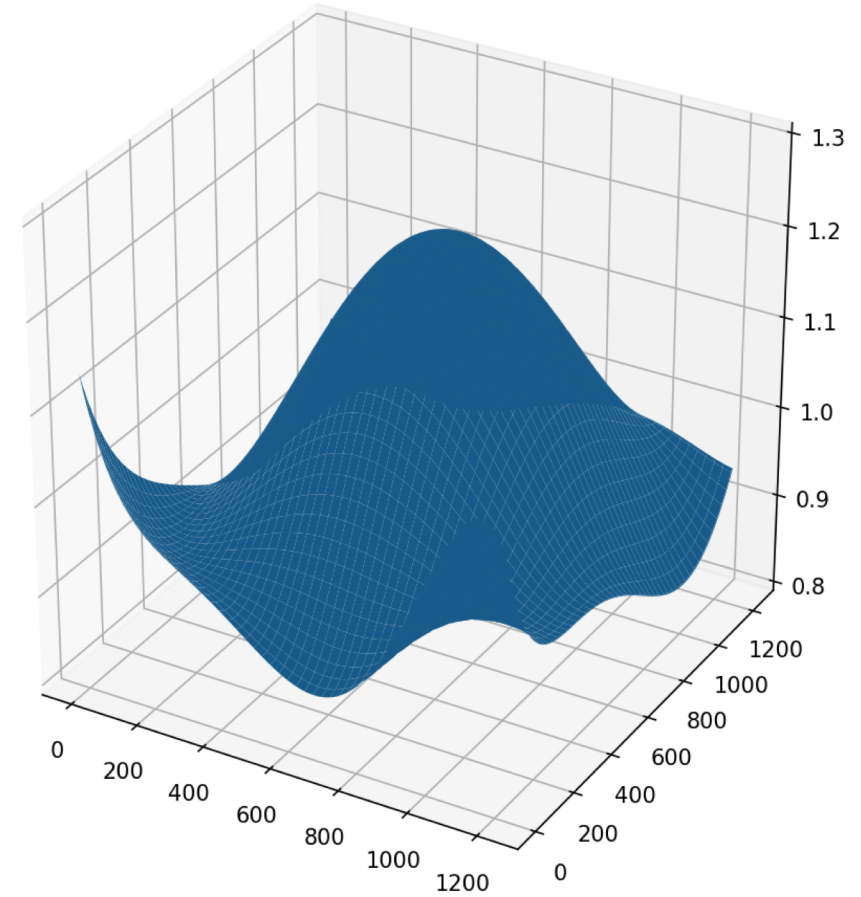
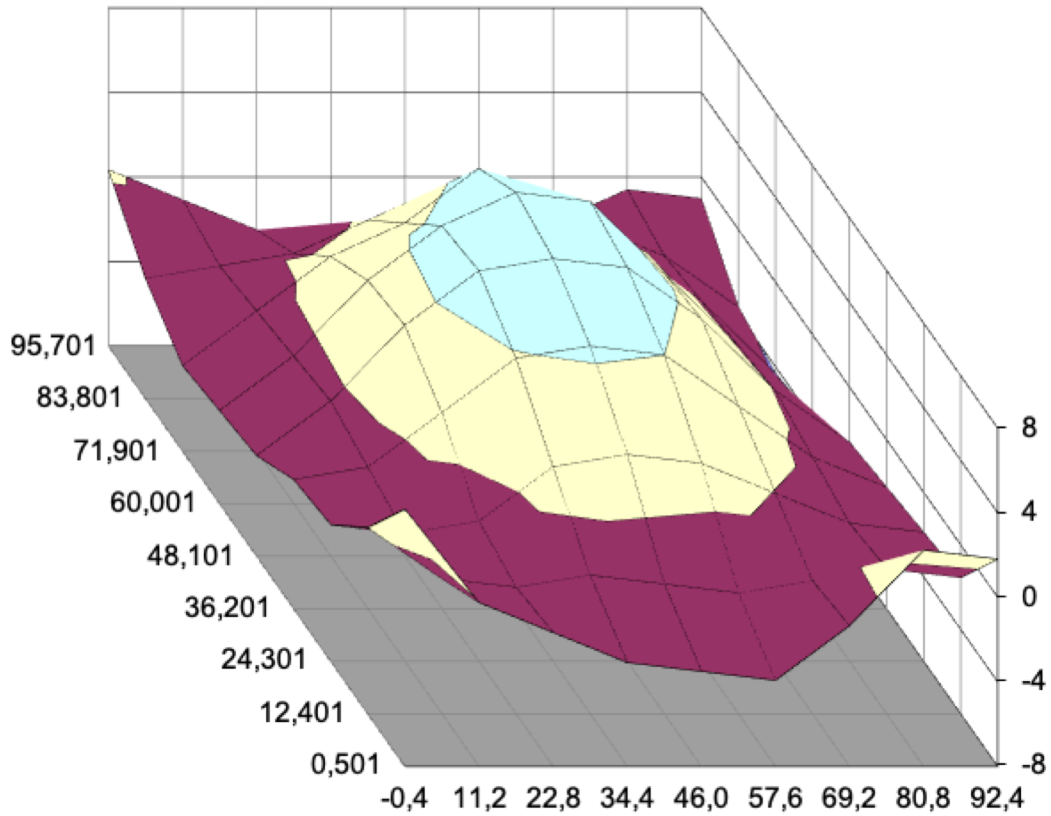
Mean fringing maps with

- $730 < \lambda < 880$ nm by steps of 0.1 nm
- $d = 30$ μm
- $r = 0.5$



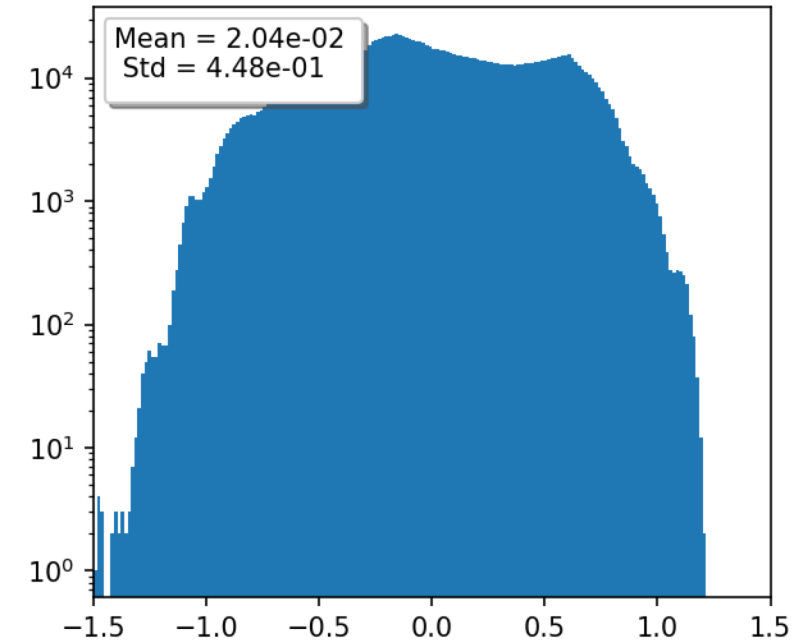
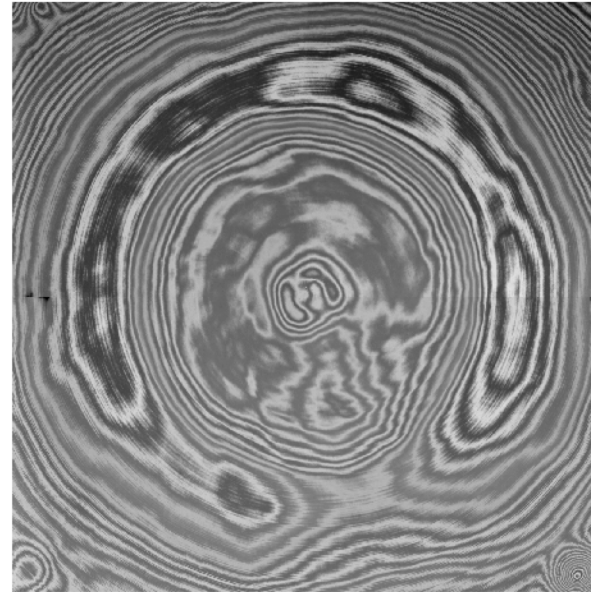
Forward modelling with e2v surface profile

From e2v data points to 2D-spline relative profile



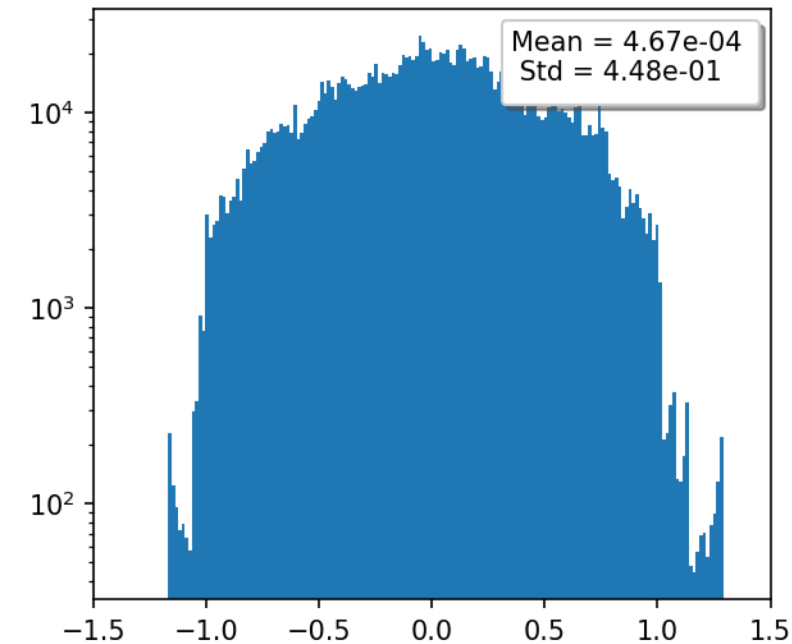
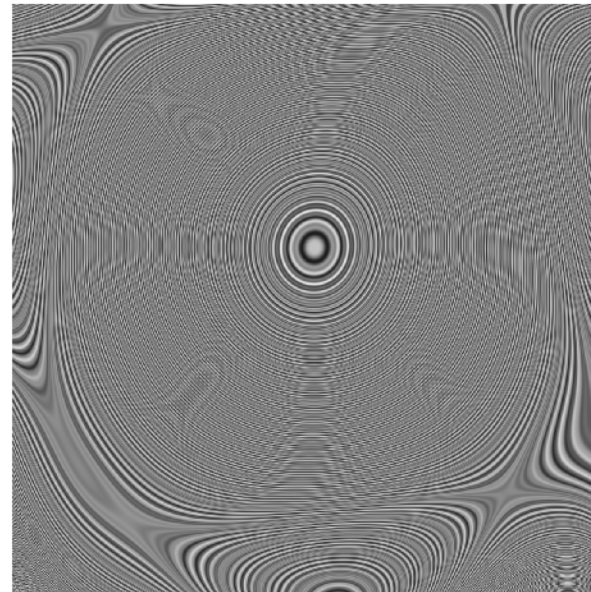
Forward modelling with e2v surface profile

CCD 01 fringing map

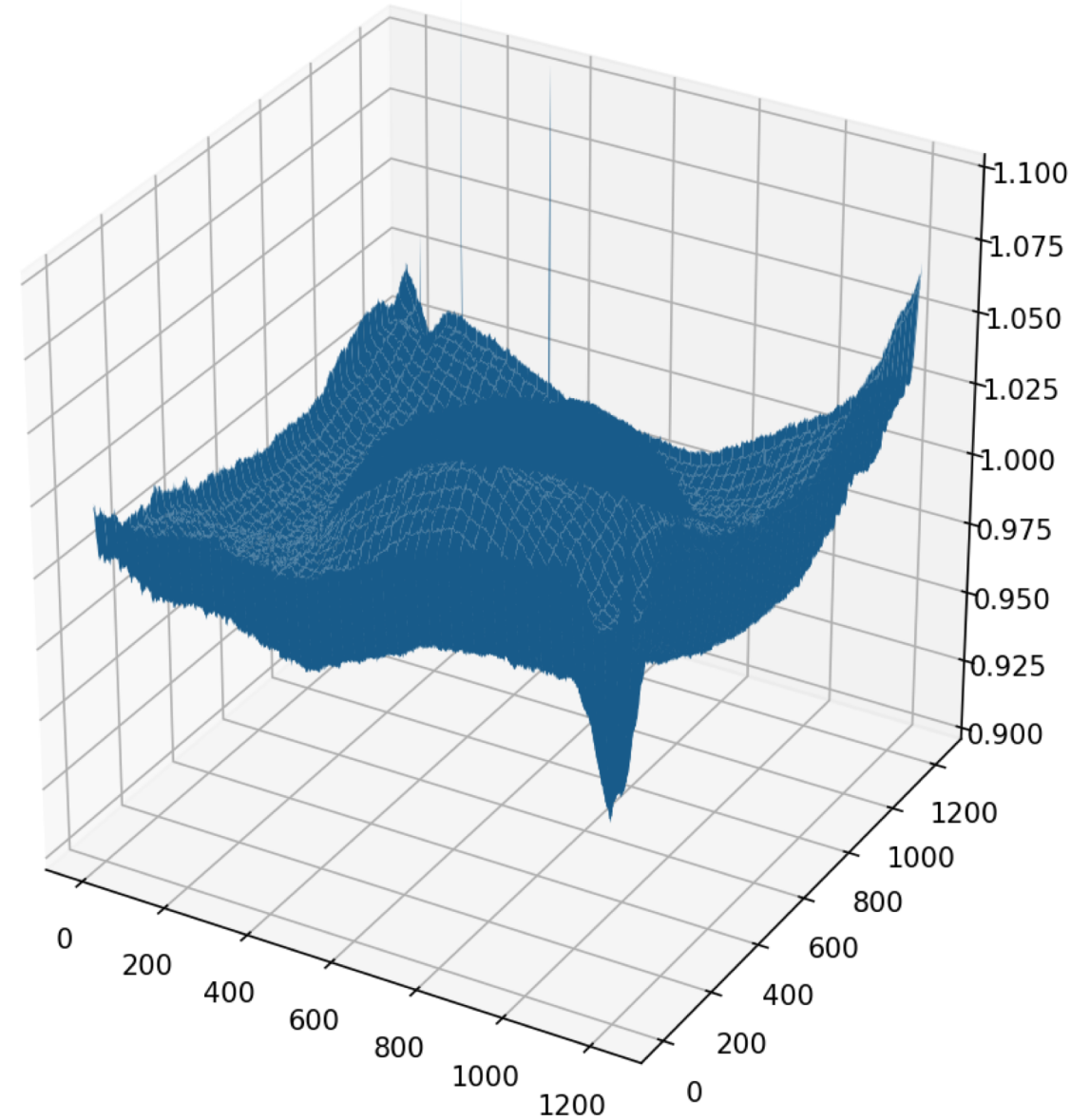
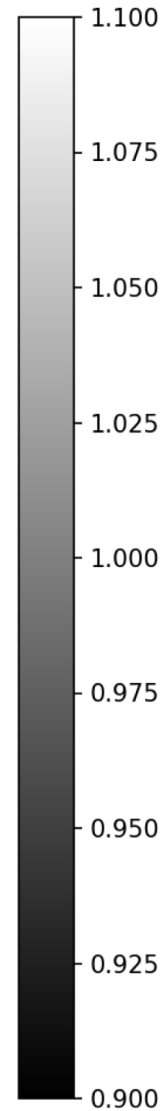
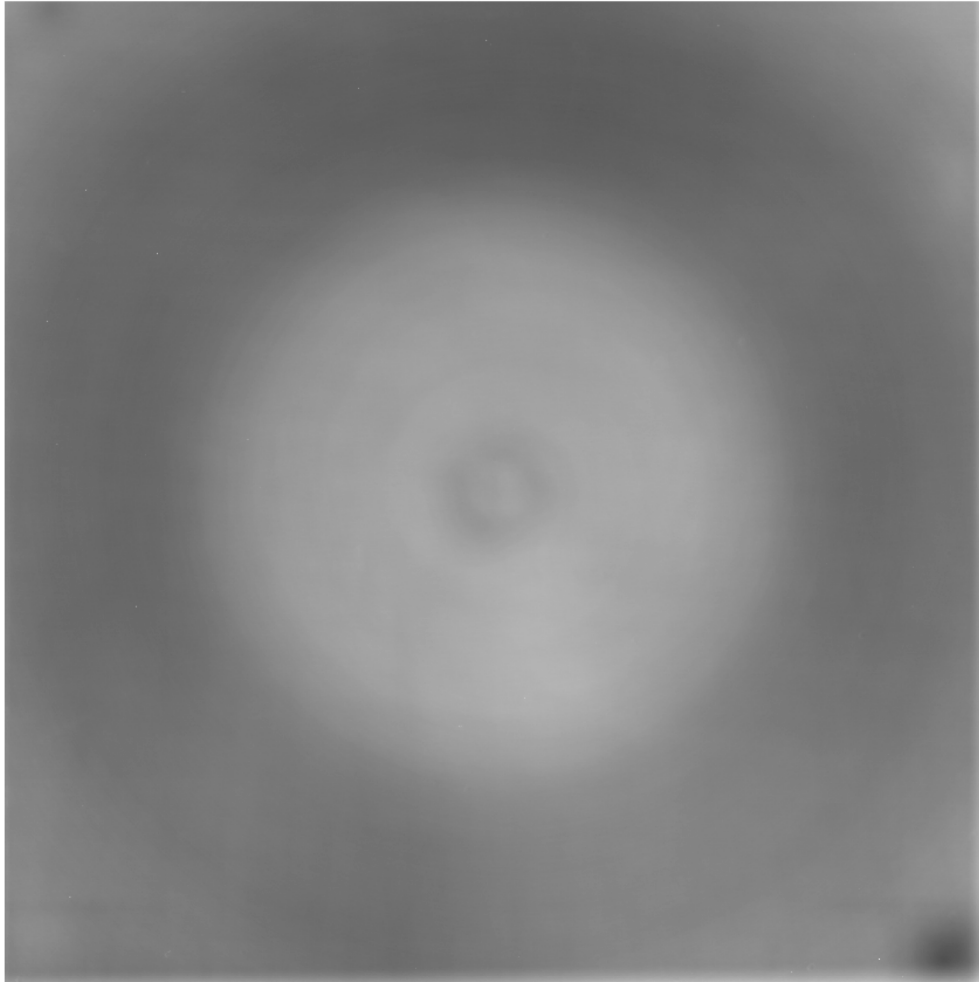


Mean fringing maps with

- $730 < \lambda < 880$ nm by steps of 0.1 nm
- $d = 30$ μm
- $r = 0.5$

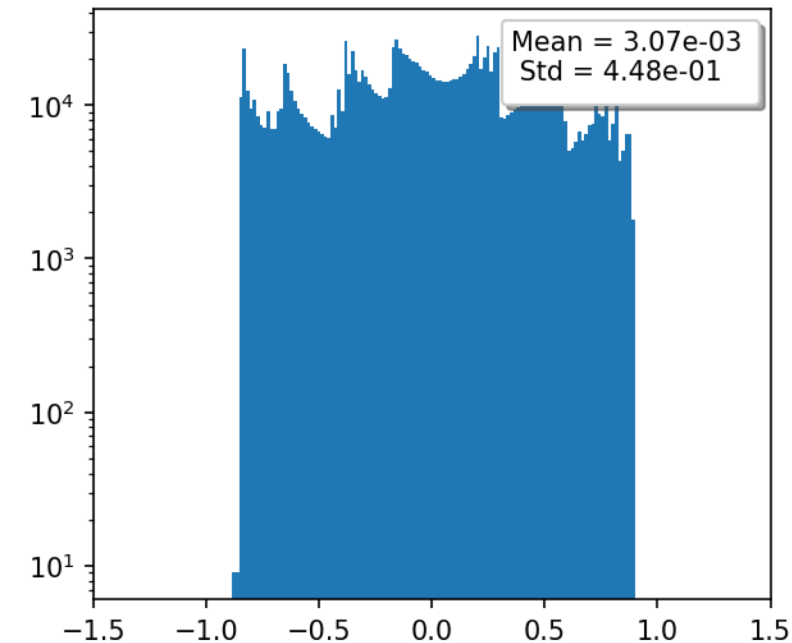
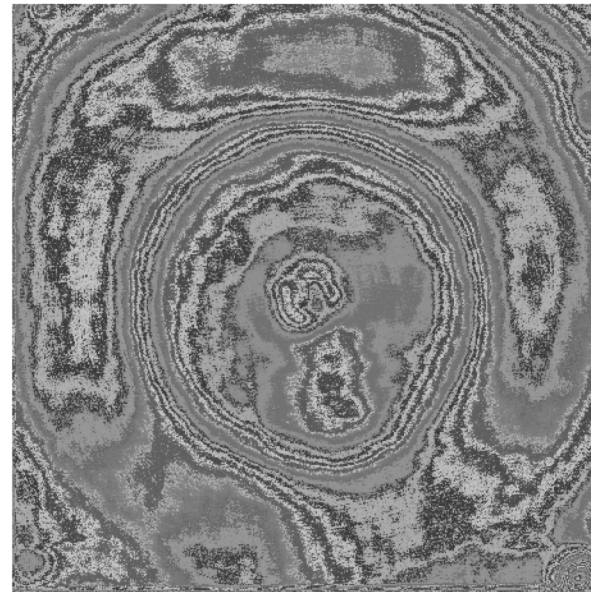
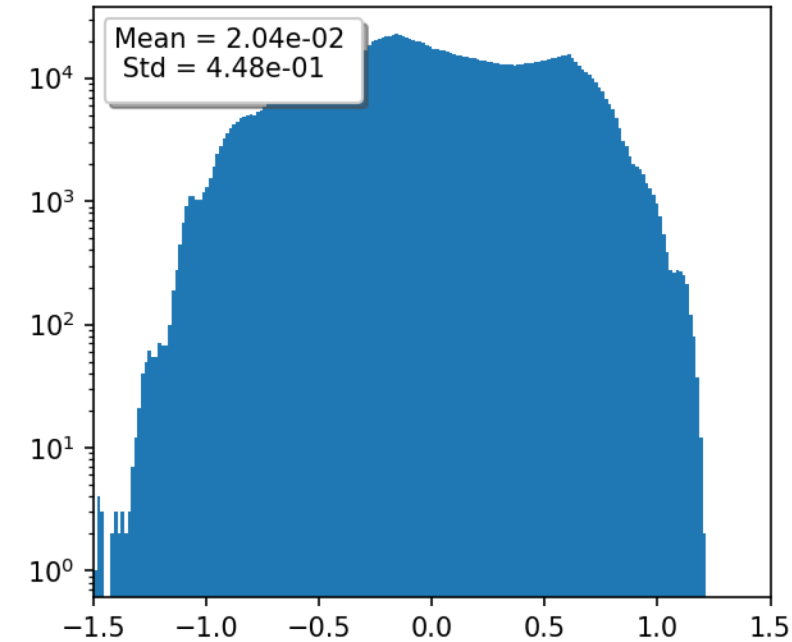
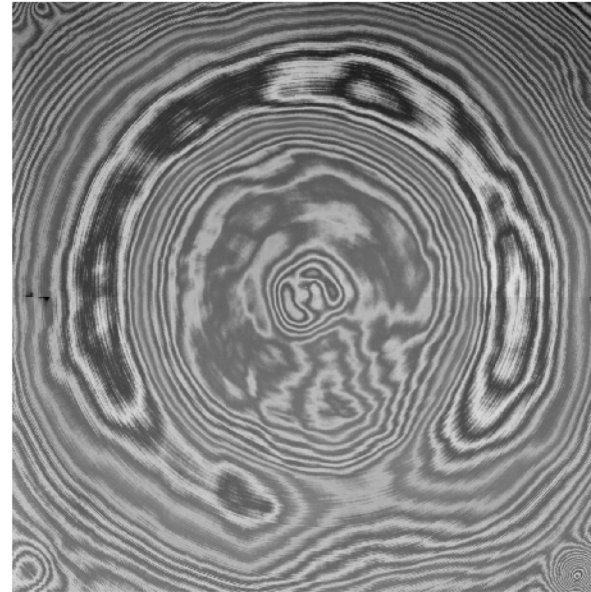


Forward modelling with profile deduce from LED ratio image = LED10 (653 nm) / LED13 (865 nm)



Forward modelling with profile from LED ratio image

CCD 01 fringing map



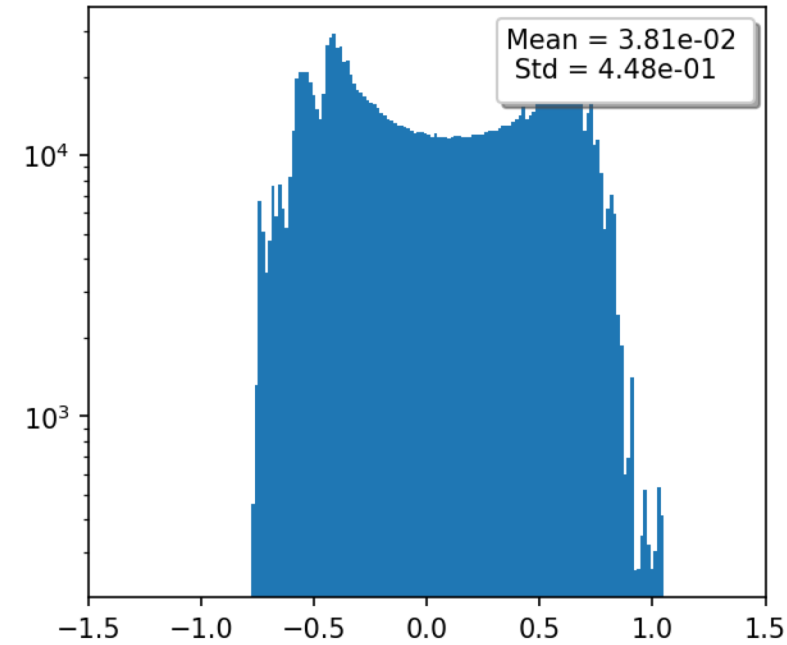
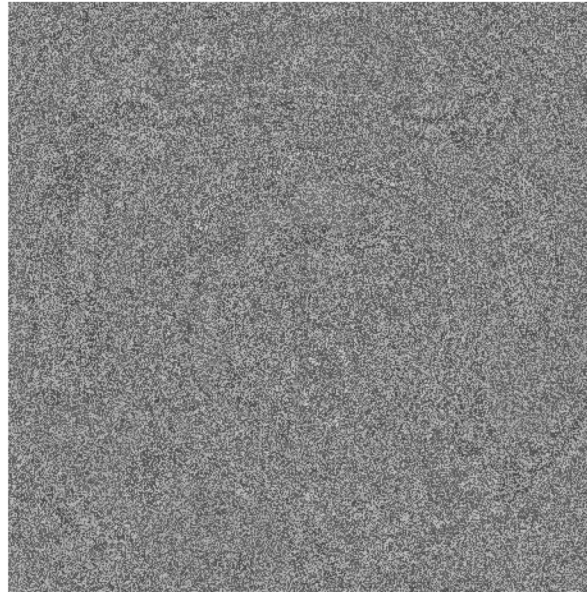
Mean fringing maps with

- $730 < \lambda < 880$ nm by steps of 0.1 nm
- $d = 30$ μm
- $r = 0.5$

Forward modelling with profile from LED ratio image

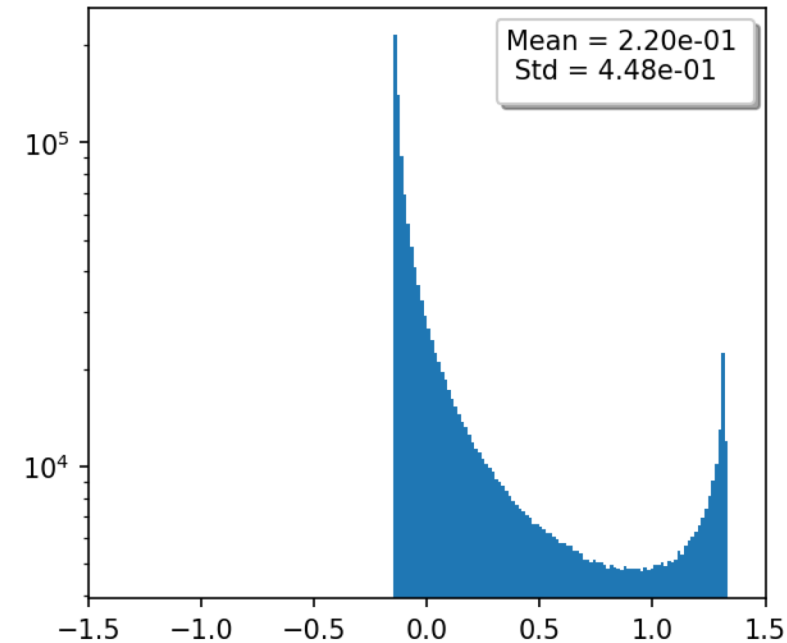
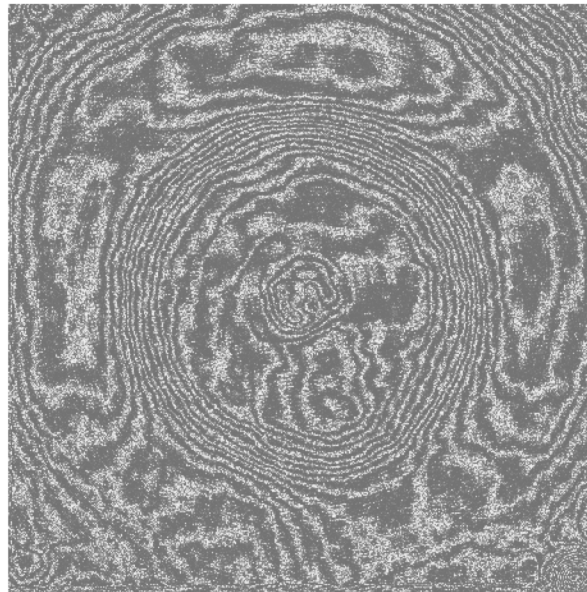
Mean fringing maps with

- $730 < \lambda < 880$ nm by steps of 1 nm
- $d = 30$ μm
- $r = 0.5$



Mean fringing maps with

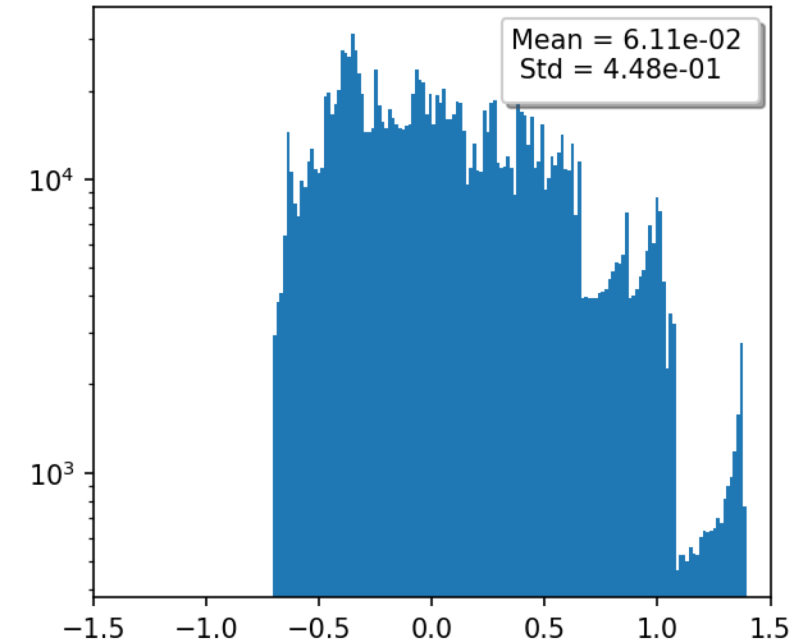
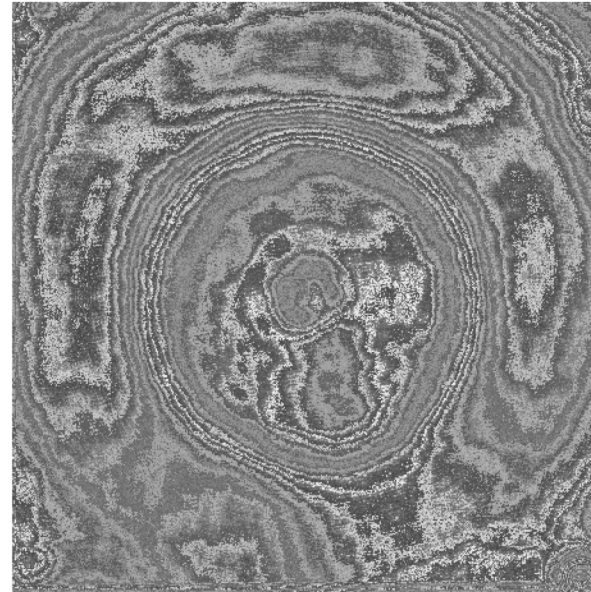
- $\lambda = 800$ nm
- $d = 30$ μm
- $r = 0.1$



Forward modelling with profile from LED ratio image

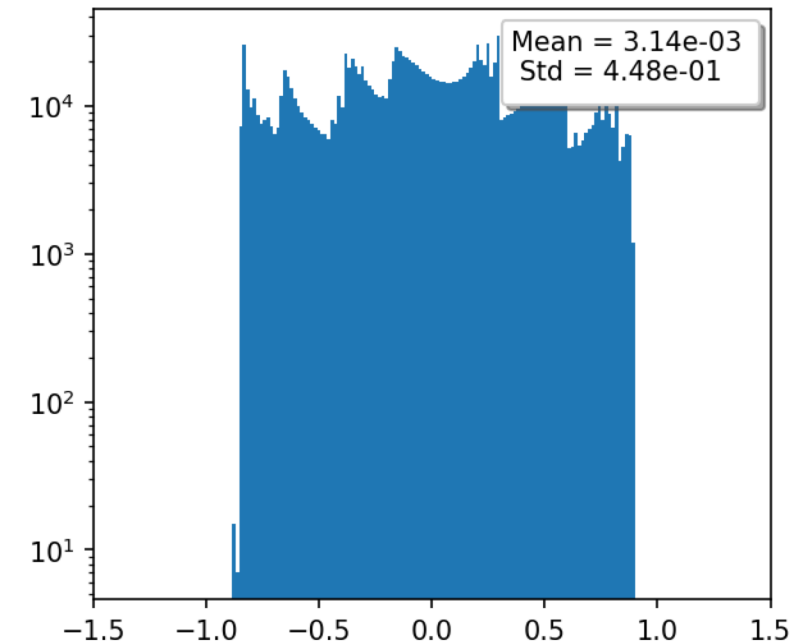
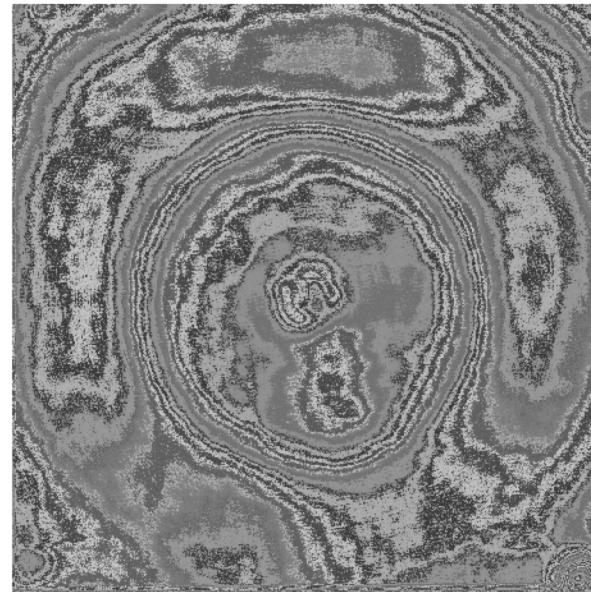
Mean fringing maps with

- $730 < \lambda < 880$ nm by steps of 10 nm
- $d = 30 \mu\text{m}$
- $r = 0.5$



Mean fringing maps with

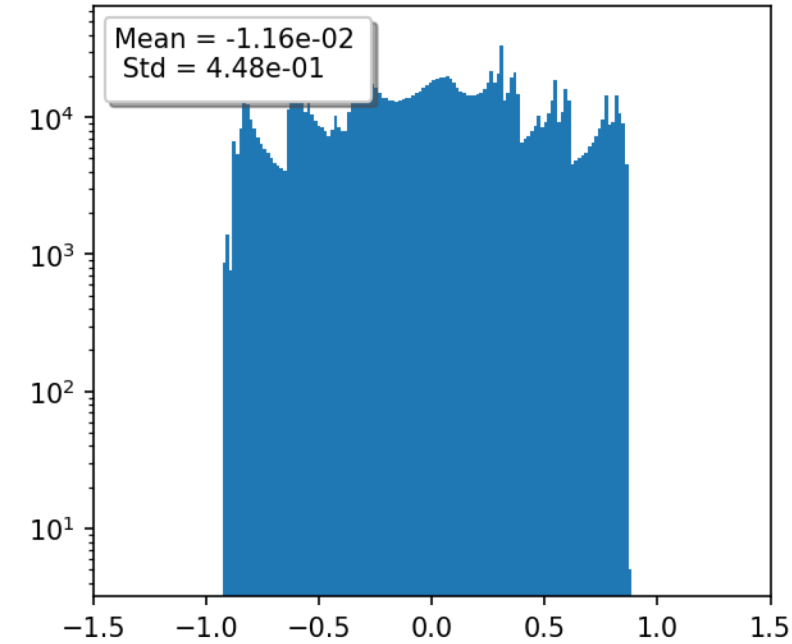
- $730 < \lambda < 880$ nm by steps of 0.01 nm
- $d = 30 \mu\text{m}$
- $r = 0.5$



Forward modelling with profile from LED ratio image

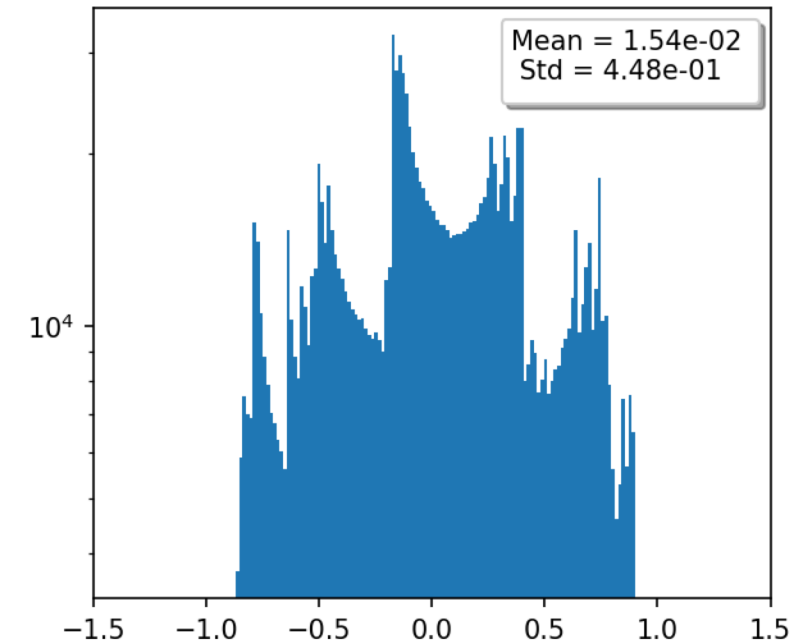
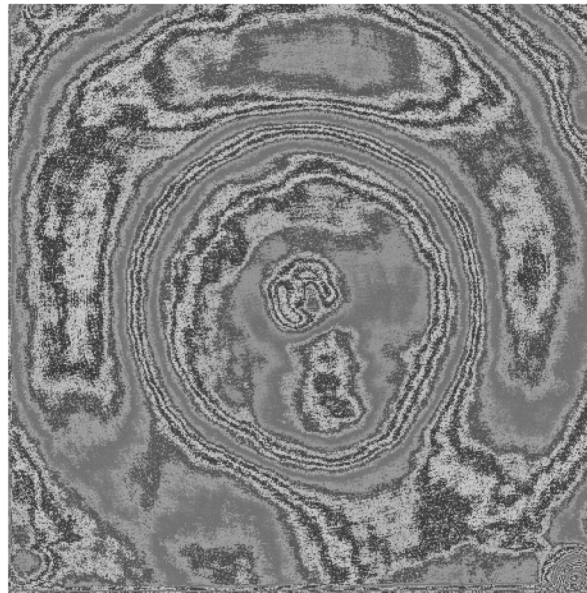
Mean fringing maps with

- $730 < \lambda < 880$ nm by steps of 0.1 nm
- $d = 20$ μm
- $r = 0.5$



Mean fringing maps with

- $730 < \lambda < 880$ nm by steps of 0.1 nm
- $d = 30$ μm
- $r = 0.1$



What next: try to take into account

- Sky spectrum
- CCD quantum efficiency

